Power IC for Quasi-Resonant Type Switching Power Supply with High Efficiency, Low Noise and Low Standby Power in Full Load Range

STR-Y6453

Sep, 2013

◆General Descriptions

The STR-Y6453 is power IC for quasi-resonant switching type power supplies, incorporating a power MOSFET and a controller IC.

The product is automatically switched to the quasi resonant operation, one bottom skip quasi resonant operation and two bottom skip operation in normal operation, and to the burst oscillation operation in light load. That realizes the low standby power and a power supply system with high cost performance, low external part count can be easily composed.

◆Features

● Multi operation mode

The operation mode switching with four steps according to load conditions achieves the optimal high efficiency and low noise power supply systems across the full range of loads.
● Current mode control method
● The built-in startup circuit reduces the power consumption
● Auto burst oscillation operation reduces dissipation.
Input power $P_{IN} \le 0.1W$ at no load
● Standby input compensation
● Overcurrent protection with AC input compensation function
● Built-in soft start function
● Built-in maximum on-time limitation circuit
● Built-in leading edge blanking function
● Avalanche energy guaranteed; two-chip structure (enabling the simplification of surge absorbing circuit)
● Protection functions
Overcurrent protection (OCP) with input compensation function: pulse by pulse basis, low dependence on input voltage
Overload protection (OLP); latched shutdown or auto restart
Overvoltage protection (OVP); latched shutdown

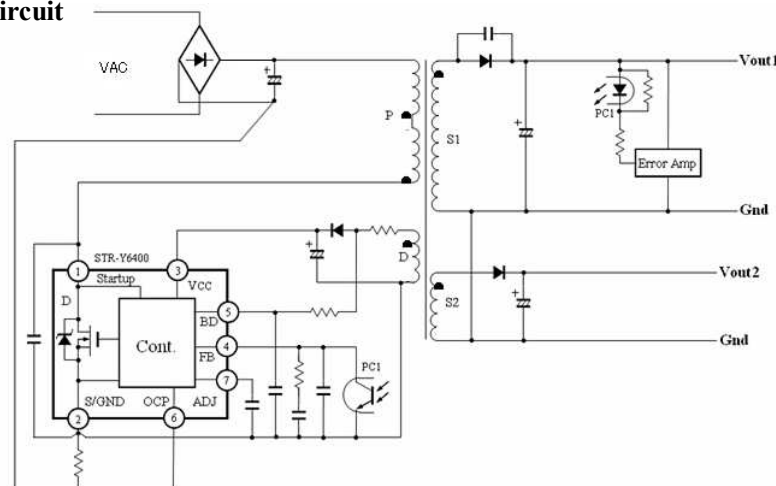## ◆Package

Package name: TO-220F-7L (FMS207)
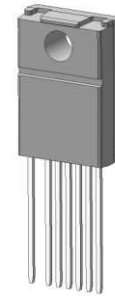
◆Application

Switching Power Supplies for
● Digital appliance such as BD/DVD recorder, FPD TVs, etc.
● OA equipments such as printer
● Home appliance (white goods)
● Industry Machines
● Communication Devices

◆Specification

MOSFET   650V, 1.8Ω(MAX)

◆Typical application circuit

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Absolute maximum ratings

- The polarity value for current specifies a sink as "+," and a source as "−," referencing the IC.
- Unless otherwise specified, T_A = 25 °C

Item	Pin	Symbol	Ratings	Unit	Remark
Drain Current	1 − 2	I_{Dpeak}[1]	10.7	A	Single pulse
Maximum Switching Current	1 − 2	I_{DMAX}[2]	10.2	A	Ta= −20 to +125°C
Avalanche Energy	1 − 2	E_{AS}[3]	62	mJ	Single pulse
					V_{DD}=99V, L=20mH I_{Lpeak}=2.3A
Control Power Supply Voltage	3 − 2	V_{CC}	32	V	
Startup Circuit pin Voltage	1 − 2	$V_{STARTUP}$	−1.0 to V_{DSS}	V	
ADJ pin Inflowing Current	7 − 2	I_{ADJ}	3.0	mA	
FB pin Inflowing Current	4 − 2	I_{FB}	8.0	mA	
BD pin Inflowing Current	5 − 2	I_{BDIN}	2.0	mA	
BD pin Inflowing Current	5 − 2	I_{BDOUT}	−2.0	mA	
OCP pin Voltage	6 − 2	V_{OCP}	−1.5 to +2.0	V	
MOS FET Power Dissipation	1 − 2	P_{D1}[4]	26	W	By infinite radiator
			1.3	W	No radiator
Control Power Dissipation (MIC)	—	P_{D2}	0.8	W	
Operating Inner Flame Temperature	—	T_F	−20 to +115	°C	Refer to recommended operating temperature
Operating Ambient Temperature	—	Top	−20 to +115	°C	
Storage Temperature	—	Tstg	−40 to +125	°C	
Channel Temperature	—	Tch	+150	°C	

[1] Refer to MOS FET A.S.O. curve
[2] Regarding the maximum switching current
   The maximum switching current is drain current IC determined by inner drive voltage and MOS FET Vth.
[3] Refer to MOS FET T_{ch}-E_{AS} curve
[4] Refer to MOS FET Ta-P_{D1} curve

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Electrical characteristics
Electrical characteristics for control part

- The polarity value for current specifies a sink as "+," and a source as "−," referencing the IC.
- Unless otherwise specified, T_A = 25 °C, V_{CC} = 20V

Characteristic	Pins	Symbol	Rating			Unit
			MIN	TYP	MAX	
Power Supply Startup Operation						
Operation Start Voltage	3 − 2	$V_{CC(ON)}$	14.4	16.2	18.4	V
Operation Stop voltage	3 − 2	$V_{CC(OFF)}$	9.0	10.0	11.3	V
Circuit Current in Operation	3 − 2	$I_{CC(ON)}$	—	3.5	5.5	mA
Circuit Current in Non-Operation	3 − 2	$I_{CC(OFF)}$	—	10	50	µA
Startup Circuit Operation Voltage	1 − 2	$V_{START(ON)}$	55	82	100	V
Startup Current	3 − 2	$I_{CC(STARTUP)}$	−2.4	−1.4	−0.5	mA
Startup Current after OLP Operation	3 − 2	$I_{CC(STARTOLP)}$	−1.10	−0.50	−0.15	mA
Oscillation Frequency	1 − 2	f_{OSC}	17.5	21.0	25.0	kHz
Soft Start Operation Stop Voltage	7 − 2	$V_{ADJ(SS)}$	2.0	2.3	2.6	V
Soft Start Operation Charging Current	7 − 2	$I_{ADJ(SS)}$	−148	−110	−71	µA
Power Off Threshold Voltage	7 − 2	$V_{ADJ(OFF)}$	8.2	9.4	10.8	V
Normal Operation						
Bottom-Skip Operation Threshold Voltage 1	6 − 2	$V_{OCP(BS1)}$	−0.720	−0.668	−0.605	V
Bottom-Skip Operation Threshold Voltage 2	6 − 2	$V_{OCP(BS2)}$	−0.485	−0.435	−0.381	V
Bottom-Skip Operation Threshold Voltage 3	6 − 2	$V_{OCP(BS3)}$	−0.205	−0.145	−0.085	V
Bottom-Skip Start Voltage	7 − 2	$V_{ADJ(BS)}$	3.8	4.3	4.8	V
Bottom-Skip Detection Bias Current	7 − 2	$I_{ADJ(BS)}$	−27	−20	−13	µA
BD Pin Maximum Clamp Voltage	5 − 2	$V_{BD(HC)}$	—	6.3	—	V
BD Pin Minimum Clamp Voltage	5 − 2	$V_{BD(LC)}$	—	−0.075	—	V
Quasi-Resonant Operation Threshold Voltage 1	5 − 2	$V_{BD(TH1)}$	0.12	0.31	0.60	V
Quasi-Resonant Operation Threshold Voltage 2	5 − 2	$V_{BD(TH2)}$	0.01	0.15	0.32	V
Maximum Feedback Current	4 − 2	$I_{FB(MAX)}$	−315	−225	−135	µA
Standby Operation						
Standby State Detection Voltage	4 − 2	$V_{FB(STBIN)}$	1.40	1.63	1.85	V
Standby State Start Voltage	7 − 2	$V_{ADJ(STB)}$	5.7	6.2	6.8	V
Standby Operation Voltage	4 − 2	$V_{FB(STBOP)}$	0.80	1.00	1.25	V
Minimum ON-time (in steady state)	1 − 2	$t_{ONL(MIN)}$	1.00	1.64	2.23	µs
Minimum ON-time (in input compensation)	1 − 2	$t_{ONH(MIN)}$	0.56	1.00	1.44	µs

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Characteristic	Pins	Symbol	Rating			Unit
			MIN	TYP	MAX	
Protection Operation						
Maximum ON –time	1 − 2	$t_{ON(MAX)}$	31	36	41	μs
Leading Edge Blanking Time	1 − 2	$t_{ON(LEB)}$	—	388	—	ns
Overcurrent Detection Threshold Voltage (in steady state)	6 − 2	$V_{OCP(H)}$	−0.975	−0.930	−0.875	V
Overcurrent Detection Threshold Voltage (in input compensation)	6 − 2	$V_{OCP(L)}$	−0.904	−0.780	−0.656	V
OCP Pin Leakage Current	6 − 2	$I_{OCP(O)}$	−260	−130	−40	μA
Input Compensation Detection Threshold Current 1	5 − 2	$I_{BD(TH1)}$	−575	−500	−425	μA
Input Compensation Detection Threshold Current 2	5 − 2	$I_{BD(TH2)}$	−565	−450	−375	μA
OLP Bias Current	4 − 2	$I_{FB(OLP)}$	−27	−20	−13	μA
OLP Auto Restart Threshold Voltage	4 − 2	$V_{FB(OLPAUTO)}$	6.3	6.7	7.3	V
OLP Latched Shutoff Bias Current	4 − 2	$I_{FB(OLPLa.OFF)}$	−1.5	−1.0	−0.5	mA
OLP Latched Shutoff Threshold Voltage	4 − 2	$V_{FB(OLPLa.OFF)}$	8.6	9.6	10.2	V
OVP Operation Power Supply Voltage	3 − 2	$V_{CC(OVP)}$	26.0	28.5	31.0	V
Latch Circuit Release Power Supply Voltage *	3 − 2	$V_{CC(La.OFF)}$	6.2	7.5	8.9	V
Maximum Voltage in Feedback Control	4 − 2	$V_{FB(MAX)}$	4.90	5.45	6.00	V
Thermal shutdown operation temperature	—	$T_{j(TSD)}$	135	—	—	°C

* The latch circuit means a circuit operated by OVP or OLP.

Electrical characteristics for MOSFET part

• Unless otherwise specified, $T_A = 25\ °C$,

Characteristic	Pins	Symbol	Rating			Unit
			MIN	TYP	MAX	
Voltage between Drain and Source	1 − 2	V_{DSS}	650	—	—	V
Drain Leakage Current	1 − 2	I_{DSS}	—	—	300	μA
ON Resistance	1 − 2	$R_{DS(ON)}$	—	—	1.8	Ω
Switching Time	1 − 2	t_f	—	—	500	ns
Thermal Resistance*	—	$\theta_{ch\text{-}F}$	—	1.0	2.0	°C/W

*Between Channel and inner frame

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A.S.O.温度ディレーティング係数曲線
A.S.O. temperature derating coefficient curve

縦軸: A.S.O.温度ディレーティング係数[%]　A.S.O. temperature derating coefficient
横軸: 内部フレーム温度 T_F [℃]　Internal frame temperature
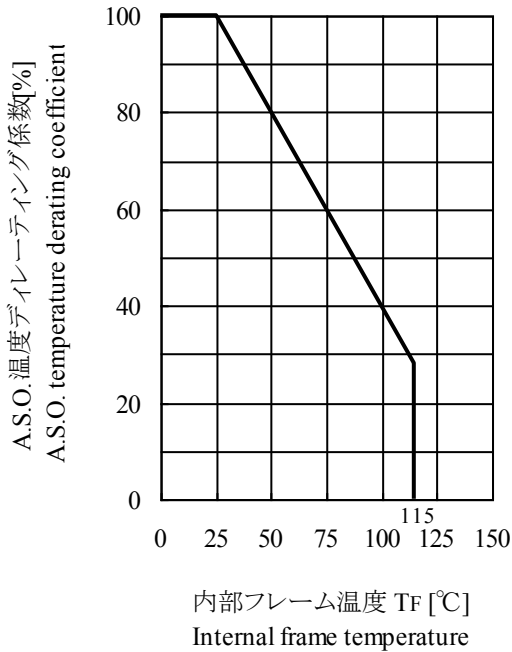
STR-Y6453
MOS FET A.S.O. 曲線　Ta=25℃
curve

シングルパルス
Single pulse

縦軸: ドレイン電流 I_D [A]　Drain Current
横軸: ドレイン・ソース間電圧　V_{DS}〔V〕　Drain-to-Source Voltage

オン抵抗による
ドレイン電流限界
Drain current limt
by ON resistance

0.1ms
1 ms

ご使用に際して左図より温度ディレーティング係数を求め、
ASOの温度ディレーティングを行って下さい。
ASO temperature derating shall be made by obtaining ASO
Coefficient from the left curve in your use.
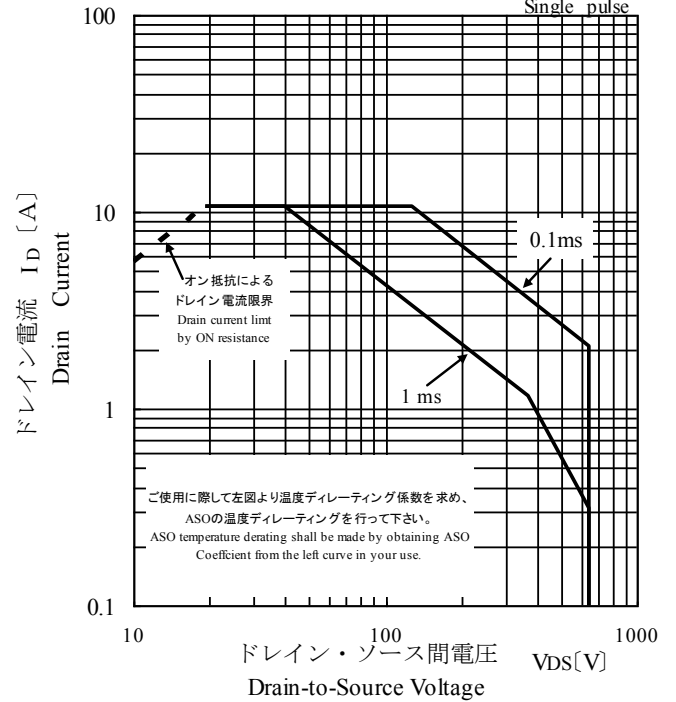
STR-Y6453
MOSFET　Ta-P_{D1}曲線
curve

縦軸: 許容損失 P_{D1} [W]　Power dissipation
横軸: 周囲温度 Ta〔℃〕　Ambient temperature

無限大放熱器付き
With infinite heat sink

放熱器なし
Without heat sink
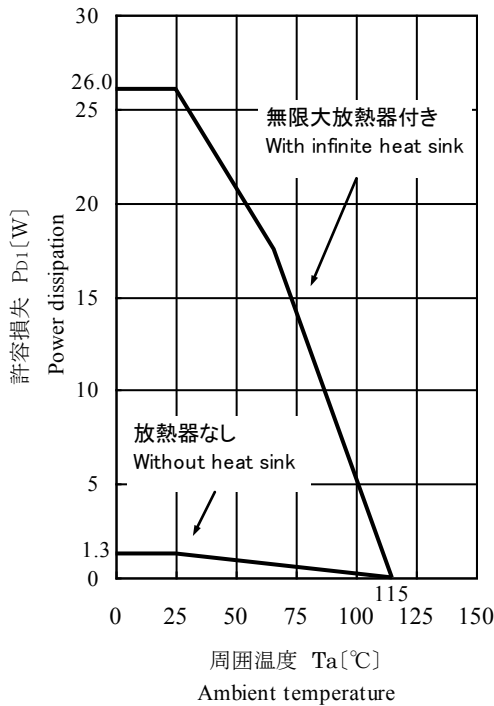
STR-Y6453
アバランシェ・エネルギ耐量
ディレーティング曲線
Avalanche energy derating curve

縦軸: E_{AS}温度ディレーティング係数[%]　E_{AS} temperature derating coefficient
横軸: チャネル温度Tch [℃]　Channel temperature

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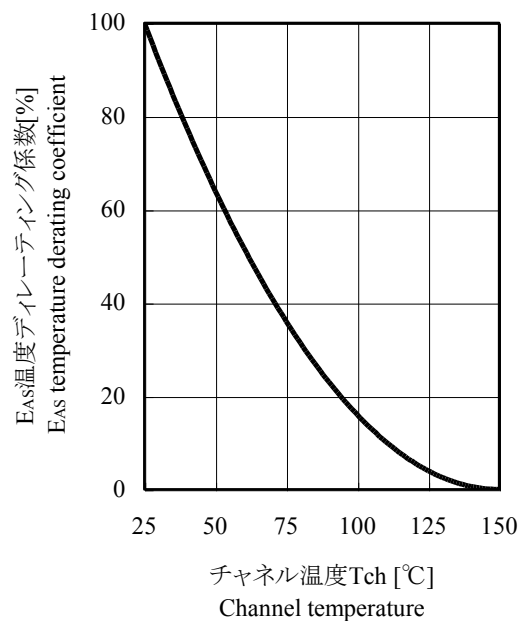
STR-Y6453 過渡熱抵抗曲線
STR-Y6453 Transient thermal resistance curve

時間 t [s]
Time

**Power IC for Quasi-Resonant Type Switching Power Supply
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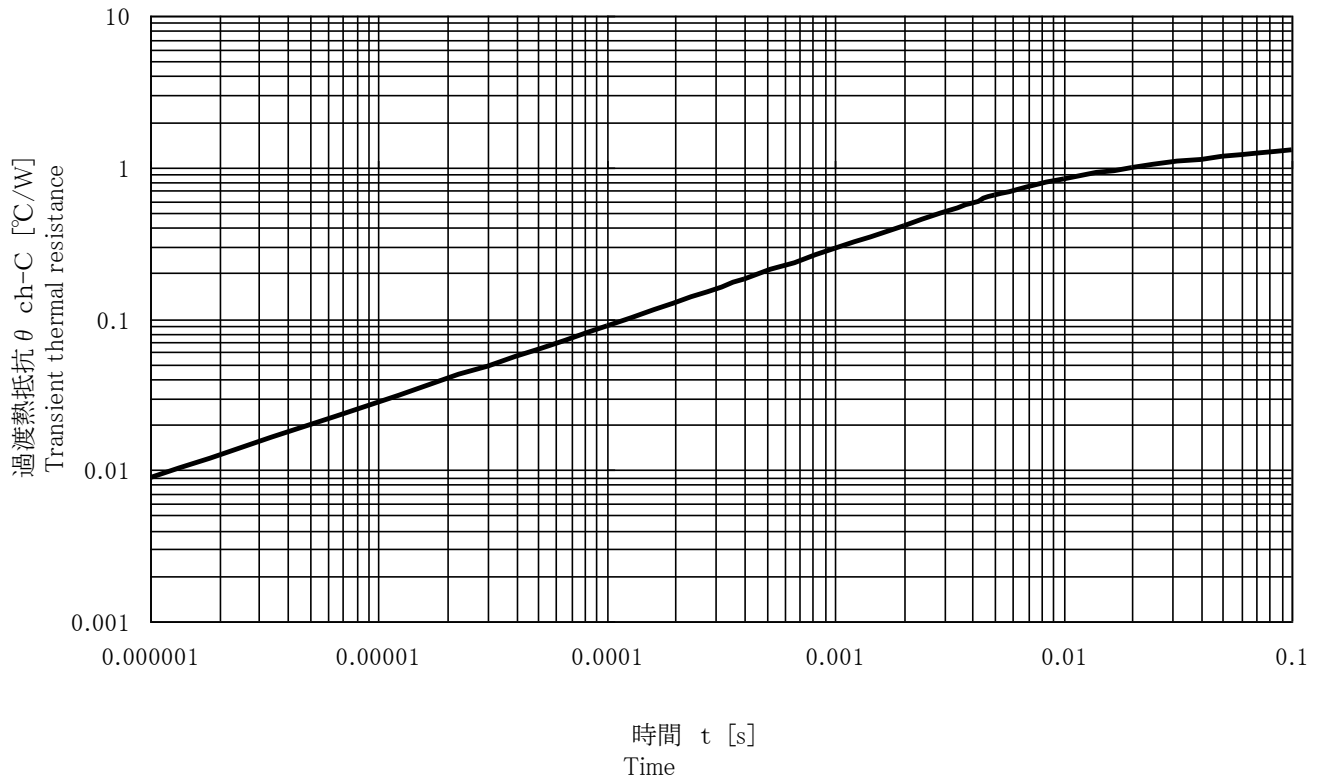
STR-Y6453

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Black Diagram
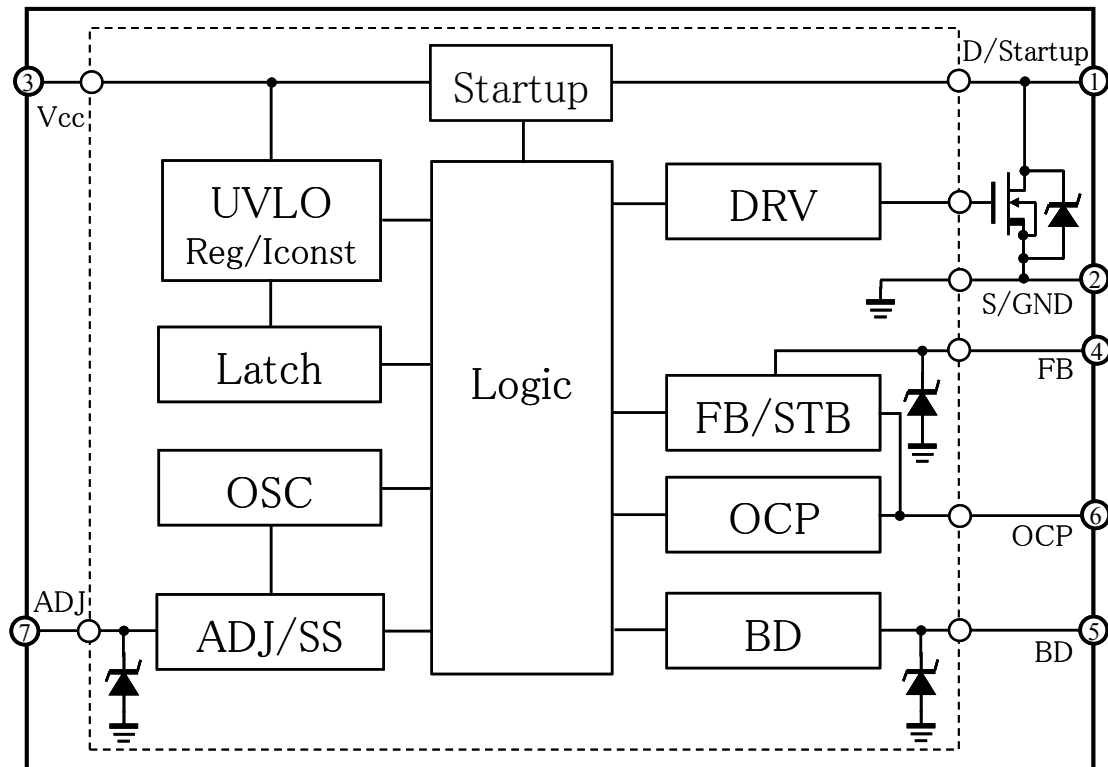
Pin function description

Pin No.	Symbol	Name	Function
1	D/Startup	Drain / Startup circuit input pin	MOSFET drain and startup circuit input
2	S/GND	Source/ Ground pin	MOSFET source and ground
3	V_{CC}	Power Supply pin	Input for power supply for control circuit
4	FB	Feedback pin	Input for Constant voltage control signal/ Standby control/ Over load detection signal
5	BD	Bottom detection/ Input compensation detection pin	Input for bottom detection signal/ Input compensation detection signal
6	OCP	Overcurrent protection input pin	Input for Overcurrent detection signal/ Bottom skip signal detection signal
7	ADJ	Adjust pin	Soft start operation/ Delay time setting of bottom skip / Input for remote ON/OFF signal
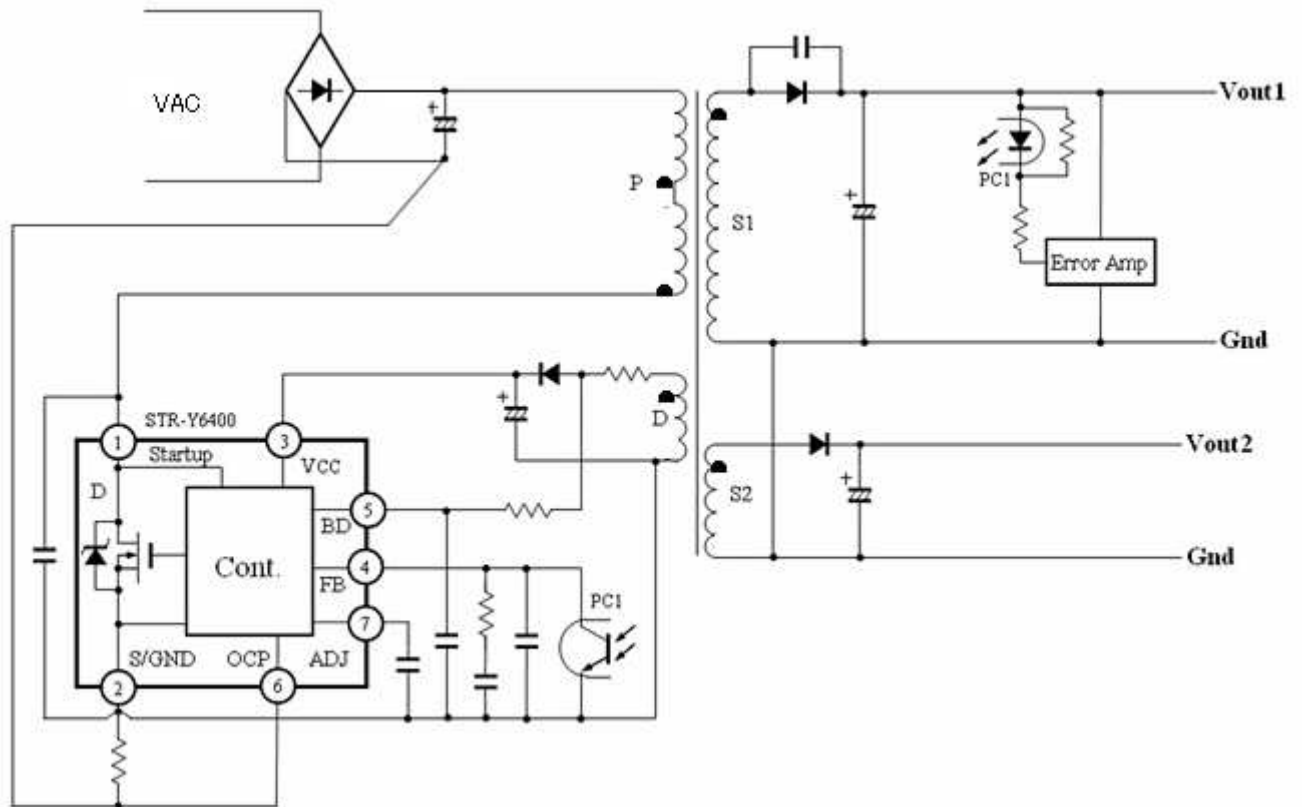
**Power IC for Quasi-Resonant Type Switching Power Supply
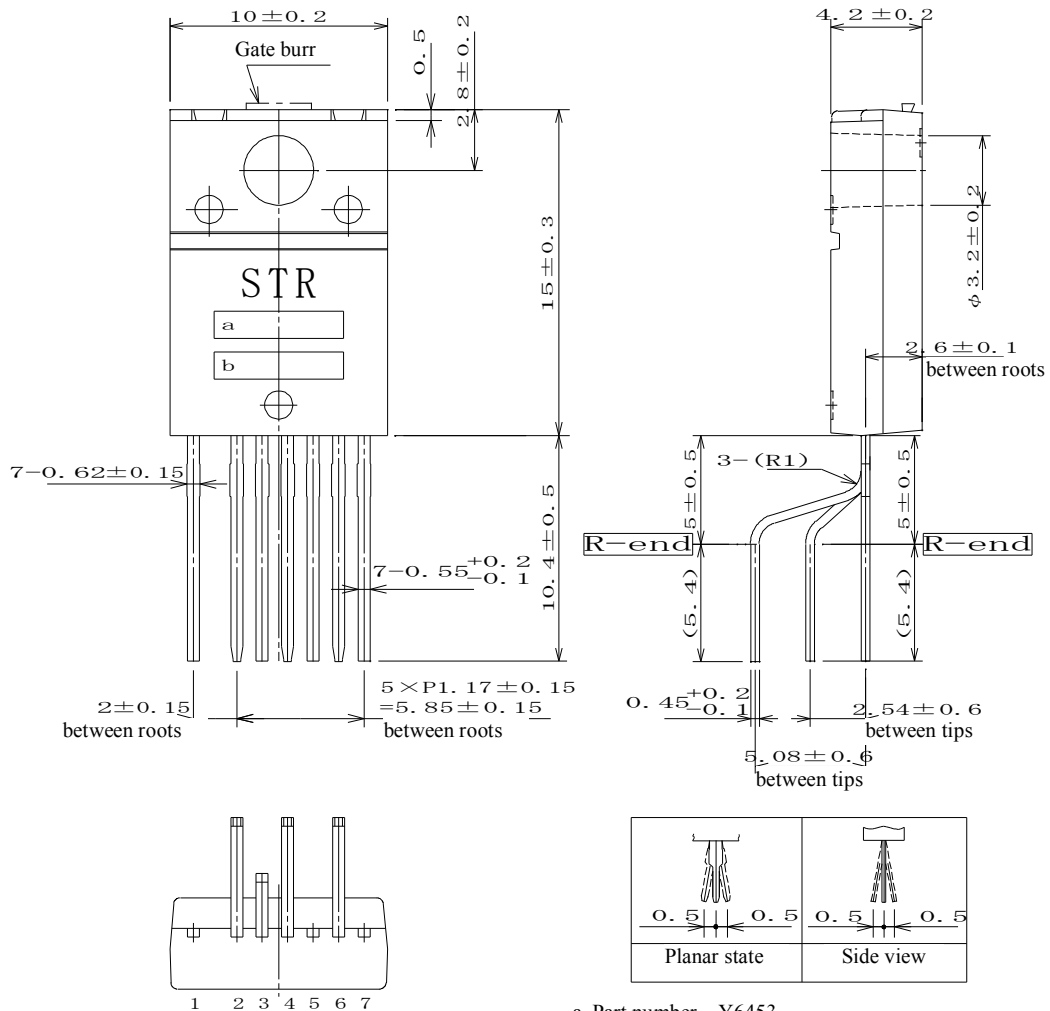with High Efficiency, Low Noise and Low Standby Power in Full Load Range**

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Typical Application Circuit

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Package

Lead forming   No. 3001

Pin material: Cu
Pin treatment: Ni plating and solder dip
Product weight (approximate): 2.3g

Note
—·— part shows the point gate burr (height 0.3 max) occurred
Dimensions in millimeters

a. Part number   Y6453
b. Lot number

1st letter: The Last digit of year
2nd letter: Month
Jan. to Sep. Arabic number
Oct.   O
Nov.   N
Dec.   D

3rd & 4th letter: day
01-31 Arabic numbers
5th letter: Sanken management symbol

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OPERATING PRECAUTIONS

In the case that you use Sanken products or design your products by using Sanken products, the reliability largely depends on the degree of derating to be made to the rated values. Derating may be interpreted as a case that an operation range is set by derating the load from each rated value or surge voltage or noise is considered for derating in order to assure or improve the reliability. In general, derating factors include electric stresses such as electric voltage, electric current, electric power etc., environmental stresses such as ambient temperature, humidity etc. and thermal stress caused due to self-heating of semiconductor products. For these stresses, instantaneous values, maximum values and minimum values must be taken into consideration. In addition, it should be noted that since power devices or IC's including power devices have large self-heating value, the degree of derating of junction temperature affects the reliability significantly.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage
- Ensure that storage conditions comply with the standard temperature (5 to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of the products that have been stored for a long time.

Cautions for Testing and Handling
When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between the product pins, and wrong connections. Ensure all test parameters are within the ratings specified by Sanken for the products.

Remarks About Using Silicone Grease with a Heatsink
- When silicone grease is used in mounting the products on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce excess stress.
- Volatile-type silicone greases may crack after long periods of time, resulting in reduced heat radiation effect. Silicone greases with low consistency (hard grease) may cause cracks in the mold resin when screwing the products to a heatsink. Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

Type	Suppliers
G746	Shin-Etsu Chemical Co., Ltd.
YG6260	Momentive Performance Materials Inc.
SC102	Dow Corning Toray Co., Ltd.

Cautions for Mounting to a Heatsink
- When the flatness around the screw hole is insufficient, such as when mounting the products to a heatsink that has an extruded (burred) screw hole, the products can be damaged, even with a lower than recommended screw torque. For mounting the products, the mounting surface flatness should be 0.05mm or less.
- Please select suitable screws for the product shape. Do not use a flat-head machine screw because of the stress to the products. Self-tapping screws are not recommended. When using self-tapping screws, the screw may enter the hole diagonally, not vertically, depending on the conditions of hole before threading or the work situation. That may stress the products and may cause failures.
- Recommended screw torque: 0.588 to 0.785 N·m (6 to 8 kgf·cm).
- For tightening screws, if a tightening tool (such as a driver) hits the products, the package may crack, and internal stress fractures may occur, which shorten the lifetime of the electrical elements and can cause catastrophic failure. Tightening with an air driver makes a substantial impact. In addition, a screw torque higher than the set torque can be applied and the package may be damaged. Therefore, an electric driver is recommended.
  When the package is tightened at two or more places, first pre-tighten with a lower torque at all places, then tighten with the specified torque. When using a power driver, torque control is mandatory.

Soldering
- When soldering the products, please be sure to minimize the working time, within the following limits:
  - 260 ± 5 °C   10 ± 1 s (Flow, 2 times)
  - 380 ± 10 °C   3.5 ± 0.5 s (Soldering iron, 1 time)
- Soldering should be at a distance of at least 1.5 mm from the body of the products.

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Electrostatic Discharge

- When handling the products, the operator must be grounded. Grounded wrist straps worn should have at least 1MΩ of resistance from the operator to ground to prevent shock hazard, and it should be placed near the operator.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in order to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in Sanken shipping containers or conductive containers, or be wrapped in aluminum foil.

IMPORTANT NOTES

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- Sanken products listed in this document are designed and intended for the use as components in general purpose electronic equipment or apparatus (home appliances, office equipment, telecommunication equipment, measuring equipment, etc.).
  When considering the use of Sanken products in the applications where higher reliability is required (transportation equipment and its control systems, traffic signal control systems or equipment, fire/crime alarm systems, various safety devices, etc.), and whenever long life expectancy is required even in general purpose electronic equipment or apparatus, please contact your nearest Sanken sales representative to discuss, prior to the use of the products herein.
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- When using the products specified herein by either (i) combining other products or materials therewith or (ii) physically, chemically or otherwise processing or treating the products, please duly consider all possible risks that may result from all such uses in advance and proceed therewith at your own responsibility.

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